# 2SB0956 (2SB956)

## Silicon PNP epitaxial planar type

For low-frequency power amplification Complementary to 2SD1280

### Features

- Large collector power dissipation P<sub>C</sub>.
- Low collector to emitter saturation voltage V<sub>CE(sat)</sub>.
- Mini Power type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

### Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	-20	V
Collector to emitter voltage	V <sub>CEO</sub>	-20	V
Emitter to base voltage	V <sub>EBO</sub>	-5	V
Peak collector current	I <sub>CP</sub>	-2	A
Collector current	$I_{C}$	-1	A
Collector power dissipation	P <sub>C</sub> *	1	W
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	<b>−55 ~ +150</b>	°C

 $<sup>^{*}</sup>$  Printed circuit board: Copper foil area of  $1 \mathrm{cm}^2$  or more, and the board thickness of 1.7mm for the collector portion

# Unit: mm 4.5±0.1 1.6±0.2 1.5±0.1 0.4±0.08 1.5±0.1 1.5±0.1 0.4±0.04 1.5±0.1 1.5±0.1 0.4±0.04 MiniP3-F1 Package

Marking symbol : H

### ■ Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = -10V, I_E = 0$			-1	μΑ
Collector to emitter voltage	V <sub>CEO</sub>	$I_{C} = -1mA, I_{B} = 0$	-20			V
Emitter to base voltage	V <sub>EBO</sub>	$I_{\rm E} = -10 \mu A, I_{\rm C} = 0$	-5			V
Forward current transfer ratio	h <sub>FE1</sub> *1	$V_{CE} = -2V, I_C = -500 \text{mA}^{*2}$	130		280	
	h <sub>FE2</sub>	$V_{CE} = -2V, I_C = -1.5A^{*2}$	50			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -1A, I_B = -50 \text{mA}^{*2}$			- 0.5	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = -500 \text{mA}, I_B = -50 \text{mA}^{*2}$			-1.2	V
Transition frequency	$f_{T}$	$V_{CB} = -6V$ , $I_E = 50$ mA, $f = 200$ MHz		200		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = -6V, I_E = 0, f = 1MHz$		40		pF

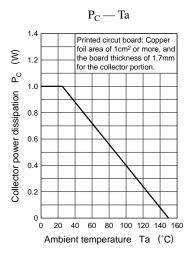
<sup>\*2</sup> Pulse measurement

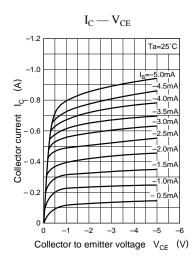
<sup>\*1</sup>h<sub>FE1</sub> Rank classification

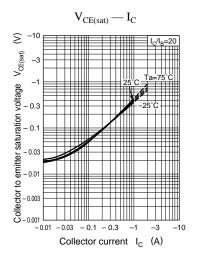
Rank	R	S		
h <sub>FE1</sub>	130 ~ 210	180 ~ 280		
Marking Symbol	HR	HS		

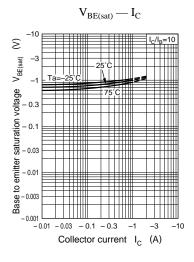
Note.) The Part number in the Parenthesis shows conventional part number.

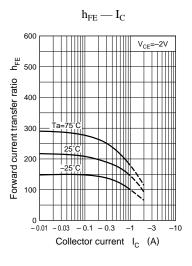
2SB0956 Panasonic

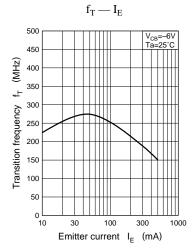


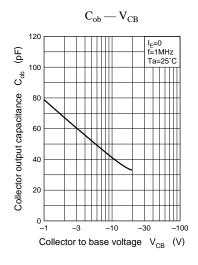


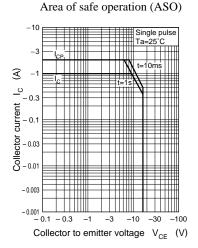












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